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## CORRECTION

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## Correction: Role of annealing temperature on the sol-gel synthesis of VO<sub>2</sub> nanowires with in situ characterization of their metal-insulator transition

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Correction for 'Role of annealing temperature on the sol-gel synthesis of VO2 nanowires with in situ characterization of their metal-insulator transition' by Y.-R. Jo et al., RSC Adv., 2018, 8, 5158-5165.

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The Royal Society of Chemistry apologises for these errors and any consequent inconvenience to authors and readers.

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